Simulation of Power Gain and Dissipation in Field-Coupled Nanomagnets



G. Csaba, A. Csurgay, P. Lugli and W. Porod



University of Notre Dame

Technische Universität München

Center for Nano Science and Technology

Lehrstühl für Nanoelektronik







The Magnetic Quantum Cellular Automata Concept







Power Gain in Nanoscale Magnets

The Quantum Cellular Automata

' () ' **Coulomb-repulsion** Driver Cell **Driven Cell** By changing the geometry one can perform logic functions as well

Main idea: Interconnection by stray fields



Magnetic Nanopillars

Bistable switch:



'()'

Due to shape anisotropy there typically few hundred а is room-temperature kT energy barrier between the two stationary states.







The Nanomagnet Wire





Clocking results in predictable switching dynamics

Micromagnetic Simulation of the Nanomagnet Wire



Η

0.5µm

Input dot: retains its magnetization

The Magnetic Majority Gate







Experimental Progress



Investigations of permalloy nanomagnets (thermally evaporated and patterned by electron beam lithography) confirm the simulation results



Approaches to Magnetic Logic Devices

Soliton – propagation Manipulation of 0000000 in coupled dots domain wall propagation 0000000 (Cowburn, Science, 2002) (Cowburn, Science, 2000) Joint ferro- and **Coupling between** magnetic vortices, antiferromagnetic coupling domain walls (Our group) **QTQŤQTQ** (Parish and Forshaw, 2003) Pictures and fabrication by A. Imre

Larger-Scale Systems



Fundamental questions from the system perspective:
What is the amount of dissipated power?
Do nanomagnets show power gain?

Model of Dissipation in Magnets



Power density:

Magnetic moments (spins) of the ferromagnetic material perform a damped precession motion around the effective field.

The Landau-Lifschitz Equation (fundamental equation of domain theory) gives quantitative description of this motion:

$$\frac{\partial \mathbf{M}(\mathbf{r},t)}{\partial t} = -\mathbf{g}\mathbf{M}(\mathbf{r},t) \times \mathbf{H}_{\text{eff}}(\mathbf{r},t)$$
$$-\frac{\mathbf{a}\mathbf{g}}{M_s} \Big[\mathbf{M}(\mathbf{r},t) \times \big(\mathbf{M}(\mathbf{r},t) \times \mathbf{H}_{\text{eff}}(\mathbf{r},t)\big) \Big]$$

Dissipative term

$$P_{\text{diss}}(\mathbf{r},t) = \mathbf{m}H_{\text{eff}} \frac{\partial M}{\partial t}\Big|_{\text{diss}} = \mathbf{m}H_{\text{eff}} \left(\frac{\mathbf{ag}}{M_s} \left[\mathbf{M}^{(i)}(\mathbf{r},t) \times \left(\mathbf{M}^{(i)}(\mathbf{r},t) \times \mathbf{H}_{\text{eff}}^{(i)}(\mathbf{r},t)\right)\right]\right)$$

Switching of a Large Magnet



Dissipation in a Domain-wall Conductor $P_{diss} \approx 10^{-7} \text{ W}$



Simulation of a 50 nm by 20 nm permalloy strip

Minimizing the Dissipation

Rapidly moving domain walls are the main source of dissipation in magnetic materials

> Make the magnets sufficiently small (submicron size magnets has no internal domain walls)

Switch them slowly (use adiabatic pumping)



Dissipation is strongest around domain walls



Small magnets have no internal domain walls

Non – Adiabatic Switching of Small Magnets



Micromagnetic Simulation of the Non-Adiabatic Switching Process



Micromagnetic simulation

 $\mathbf{M}(\mathbf{r},t)$



Adiabatic Switching



By adiabatic clocking, the system can be switched with almost no dissipation, but at the expense of slower operation.

Switching +M_s



Dynamic simulation

 $\mathbf{M}(\mathbf{r},t)$



Switching Speed vs. Dissipated Power



Adiabatically switched nanomagnets can dissipate at least two orders of magnitude less energy than the height of the potential barrier separating their steady-states

The Lowest Limit of Dissipation in Magnetic QCA



Deviations from the ideal single-domain behavior - \rightarrow abrupt domain wall switches will always cause dissipation (few kT)



Coupling between dots should be stronger than few $kT \rightarrow$ dot switching cannot be arbitrarily slow \rightarrow few kT dissipation unavoidable

The minimal dissipation of nanomagnetic logic devices is around a few kT per switching.



Detailed View of the Switching Process



Energy of the magnetic signal increases as the soliton propagates along the wire



Hysteresis Curves of Single-Domain Nanomagnets



A Nanomagnet Driven by Current Loops





This is a circuit with a variable inductance. Does it have applications?

Magnetic Amplifiers

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Fig. 1-1. Packaged magnetic amplifiers. (Courtesy, Magnetic Research Corporation.)

Nonlinearity of the hysteresis curve \rightarrow Tunable inductances \rightarrow Power gain

Magnetic Computers



This three-coil device behaves like a common-base transistor amplifier



A magnetic shift register from Gschwind: Design of Digital Computers, 1967



Coupled Nanomagnets as Circuits



The origin of power gain in field-coupled nanomagnets can be understood on the same basis as the operation of magnetic parametric amplifiers → Nanoelectronic circuit design

Conclusions

1.0µm



1cm

Magnetic field-coupling is an idea worth pursuing...

Low dissipation, robust operation, high integration density and reasonably high speed

As they are active devices, there is no intrinsic limit to their scalability

Field-coupling is functionally equivalent to electrically interconected device architectures

Our Group

Prof. Wolfgang Porod Prof. Paolo Lugli Prof. Arpad Csurgay (Circuit modeling) Prof. Gary H. Bernstein (Experiments) Prof. Vitali Metlushko

(Fabrication)

Prof. Alexei Orlov

(Electrical measurements)

Alexandra Imre

(Fabrication, Characterization)

Ling Zhou

(Electrical measurements)

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